

PMBTA44,215 Datasheet



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DiGi Electronics Part Number PMBTA44,215-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PMBTA44,215

Description TRANS NPN 400V 0.3A TO236AB

Detailed Description Bipolar (BJT) Transistor NPN 400 V 300 mA 20MHz 2

50 mW Surface Mount TO-236AB



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PMBTA44,215	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	300 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
400 V	750mV @ 5mA, 50mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	50 @ 10mA, 10V
Power - Max:	Frequency - Transition:
250 mW	20MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	TO-236AB
Base Product Number:	
PMBTA44	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



PMBTA44

400 V, 0.3 A NPN high-voltage low VCEsat transistor **Product data sheet**

1. General description

NPN high-voltage low V_{CEsat} transistor in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low current (max. 300 mA)
- High voltage (max. 400 V)

3. Applications

- LED driver for LED chain module
- LCD backlighting
- · High Intensity Discharge (HID) front lighting
- Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	400	V
I _C	collector current		-	-	300	mA
h _{FE}	DC current gain	$V_{CE} = 10 \text{ V}; I_{C} = 10 \text{ mA}; T_{amb} = 25 \text{ °C}$	50	-	200	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base]3	С
2	Е	emitter		j
3	С	collector		В — (
			SOT23	 E sym021



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6. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
PMBTA44	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23	

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PMBTA44	W3%

[1] % = placeholder for manufacturing site code

8. Limiting values

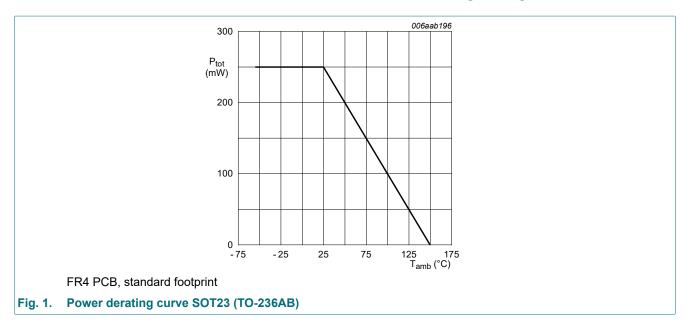
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	500	V
V _{CEO}	collector-emitter voltage	open base		-	400	V
V_{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	300	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	300	mA
I _{BM}	peak base current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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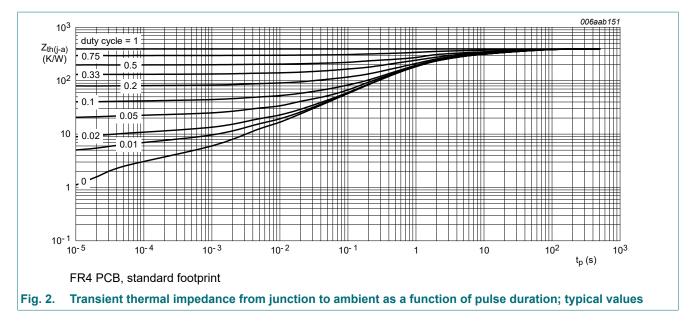


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uily-a)	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = 320 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CB} = 320 V; I _E = 0 A; T _j = 150 °C	-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 4 V; I _C = 0 A; T _{amb} = 25 °C	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 10 V; I _C = 10 mA; T _{amb} = 25 °C	50	-	200	
		V_{CE} = 10 V; I_{C} = 50 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	45	-	-	
		V_{CE} = 10 V; I_{C} = 100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	40	-	-	
V _{CEsat}	Esat collector-emitter	I _C = 1 mA; I _B = 0.1 mA; T _{amb} = 25 °C	-	-	400	mV
	saturation voltage	I _C = 10 mA; I _B = 1 mA; T _{amb} = 25 °C	-	-	500	mV
		I_C = 50 mA; I_B = 5 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	750	mV
V _{BEsat}	base-emitter saturation voltage	I_C = 10 mA; I_B = 1 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	850	mV
f _T	transition frequency	V_{CE} = 10 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	20	-	-	MHz
C _c	collector capacitance	V_{CB} = 20 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	7	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_{C} = 0 \text{ A}; i_{c} = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	-	180	pF

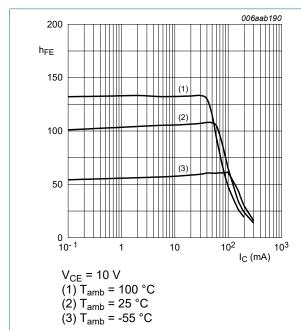


Fig. 3. DC current gain as a function of collector current; typical values

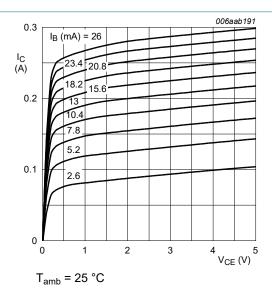


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

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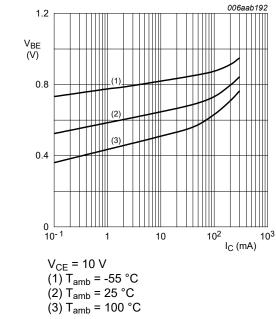


Fig. 5. Base-emitter voltage as a function of collector current; typical values

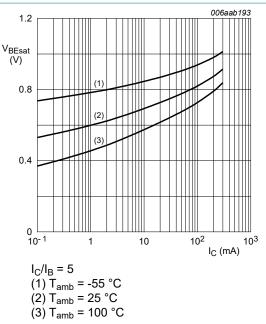
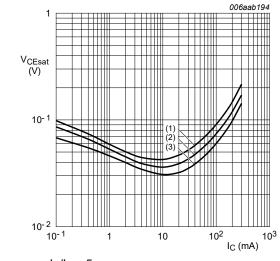


Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



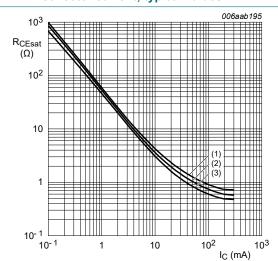
 $I_{\rm C}/I_{\rm B}=5$

(1) T_{amb} = 100 °C

(2) T_{amb} = 25 °C

(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_C/I_B = 5$

(1) T_{amb} = 100 °C

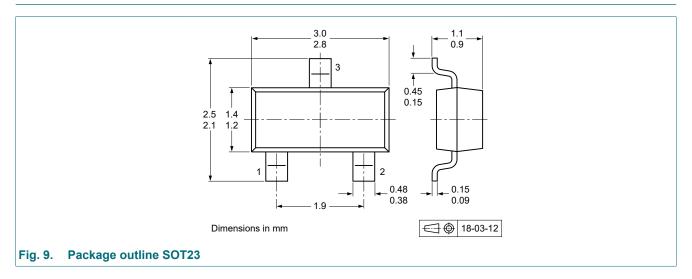
(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55 \, ^{\circ}C$

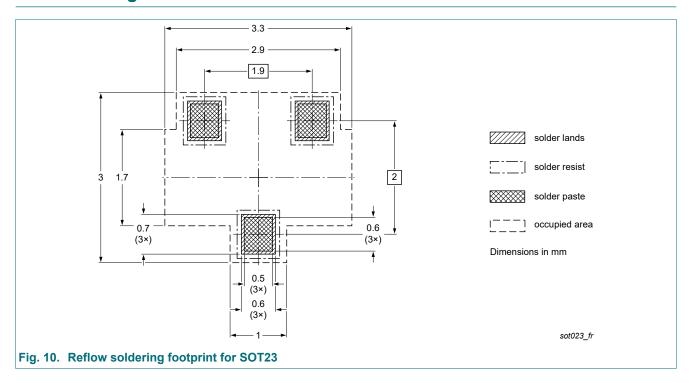
Fig. 8. Collector-emitter saturation resistance as a function of collector current; typical values

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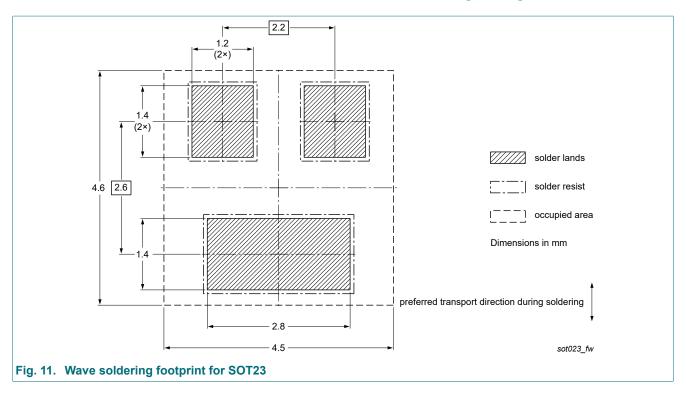
11. Package outline



12. Soldering



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13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMBTA44 v.2	20230101	Product data sheet	-	PMBTA44 v.1
Modifications:	Nexperia. • Legal texts ha	this data sheet has been rede ve been adapted to the new o ged to non-automotive qualific lternative(s).	ompany name where	appropriate.
PMBTA44 v.1	20080222	Product data sheet	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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